

$^{70}\text{Ga } \varepsilon \text{ decay }$     [\*\*1977Sc10\*\*](#)

Type	Author	History	Citation	Literature Cutoff Date
Full Evaluation	G. Gürdal, E. A. Mccutchan		NDS 136, 1 (2016)	1-Jul-2016

Parent:  $^{70}\text{Ga}$ : E=0.0;  $J^\pi=1^+$ ;  $T_{1/2}=21.14$  min 3;  $Q(\varepsilon)=654.6$  16;  $\% \varepsilon \text{ decay}=0.41$  5

$^{70}\text{Ga}-\varepsilon$  decay: From ratio of Zn K $\alpha$  x rays to I $\gamma(176\gamma)$  in  $^{70}\text{Ge}$  ([1977Sc10](#)). Ratio corrected for contamination of  $^{68}\text{Ga}$  in the measured activity. Other: 0.24% ([1975Bu07](#), earlier result from the same laboratory as [1977Sc10](#)).

**1977Sc10:**  $^{70}\text{Ga}$  activity from  $^{69}\text{Ga}(\text{d},\text{p})$  with E(d)=8.8, 10.4, and 11.9 MeV. Branching ratio measurement performed at 8.8 MeV. Measured E $\gamma$ , I $\gamma$ ,  $\gamma(t)$ , K $\alpha$  x-ray using Ge(Li) detector.

Others: [1975Bu07](#), [1957Bu41](#).

 $^{70}\text{Zn Levels}$ 

E(level)	$J^\pi \dagger$	$T_{1/2} \dagger$
0.0	$0^+$	$\geq 3.8 \times 10^{18}$ y

$\dagger$  From the Adopted Levels.

 $\varepsilon$  radiations

E(decay)	E(level)	$I\varepsilon \dagger$	Log $f_t$	Comments
(654.6 16)	0.0	100	4.72 6	$\varepsilon K=0.8828$ ; $\varepsilon L=0.09946$ ; $\varepsilon M+=0.01774$

$\dagger$  For absolute intensity per 100 decays, multiply by 0.0041 5.